



### Chip Termination 100 Watts, 50Ω



### Features:

- RoHS Compliant
- 100 Watts
- DC 3.5 GHz
- AIN Ceramic
- Non-Nichrome Resitive Element
- Low VSWR
- 100% Tested
- Small Size

### **Description:**

The A100N50X4A is high performance Aluminum Nitride (AIN) chip termination intended as an alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators and for use in power combiners. The termination is also RoHS compliant!

### **General Specifications:**

Resistive Element	Thick film
Substrate	AIN Ceramic
Terminal Finish	Matte Tin over Nickel Barrier
Operating Temperature	-55 to +150°C (see de rating chart)

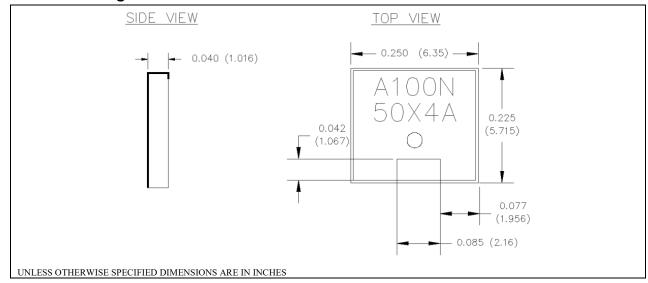
Tolerance is  $\pm 0.010^{\circ}$ , unless otherwise specified. Designed to meet or exceed applicable portions of MIL-E-5400. All dimensions in inches.

### **Electrical Specifications:**

Resistive Value:	50 Ohms, ± 2%
Power:	100 Watts
Frequency Range:	DC – 3.5 GHz
V.S.W.R:	1.12 : 1 DC – 3.0 GHz
	1.22 : 1 DC – 3.5 GHz

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.** 

### **Outline Drawing:**





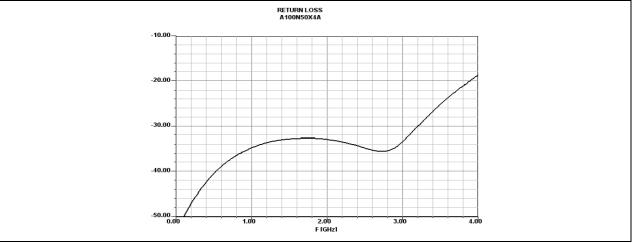
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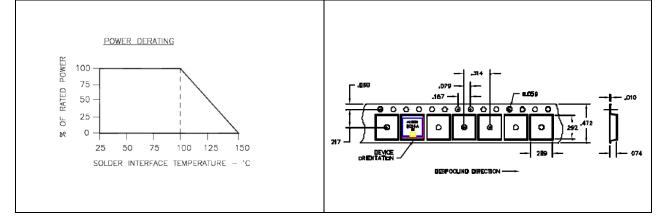


### **Typical Performance:**

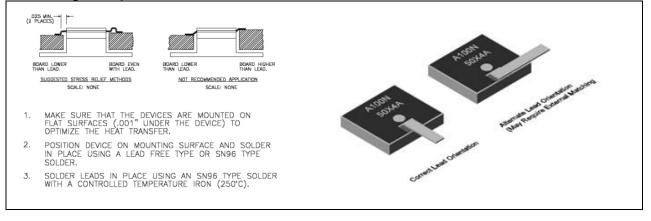


Tape & Reel Available

### Power de-rating:



### **Mounting Footprint and Procedure:**



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